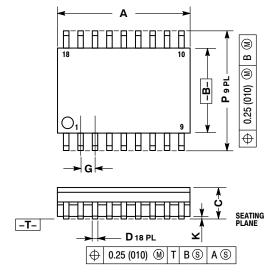
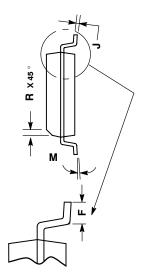


18 LEAD WIDE BODY SOIC CASE 751C-04 **ISSUE F**

SCALE 1:1



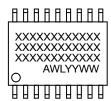


DATE 09/29/20	000
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NOTES:

- 1. DIMENSIONS A AND B ARE DATUMS AND T IS A DATUM SURFACE.
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 114.5M, 1982. 3. CONTROLLING DIMENSION: MILLIMETER. 4. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION. 5. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER
- MAAMUM MOLD PROTHUSION 0.15 (0.006) PEH SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION MATERIAL CONDITION.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	11.40	11.70	0.449	0.460
В	7.40	7.60	0.292	0.299
C	2.35	2.65	0.093	0.104
D	0.35	0.49	0.014	0.019
F	0.50	0.90	0.020	0.035
G	1.27 BSC		0.050 BSC	
J	0.25	0.32	0.010	0.012
K	0.10	0.25	0.004	0.009
М	0°	7°	0 °	7°
Ρ	10.05	10.55	0.395	0.415
R	0.25	0.75	0.010	0.029



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DESCRIPTION:	18 LD W/B SOIC		PAGE 1 OF 1	

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